



DMP2007UFG

#### 20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI<sup>®</sup>

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C
	$5.5m\Omega @ V_{GS} = -10V$	-40A
-20V	7.0mΩ @ V <sub>GS</sub> = -4.5V	-40A
	9.0mΩ @ V <sub>GS</sub> = -2.5V	-40A

## Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high- efficiency power management applications.

# Applications

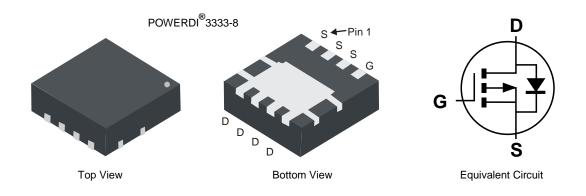
- Load Switch
- Power Management Functions

#### Features

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# **Mechanical Data**

- Case: POWERDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.030 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2007UFG-7	POWERDI3333-8	2,000/Tape & Reel
DMP2007UFG-13	POWERDI3333-8	3,000/Tape & Reel

Notes: 1

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



S43 = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 14 = 2014) WW = Week Code (01 ~ 53)

POWERDI is a registered trademark of Diodes Incorporated DMP2007UFG Document number: DS37943 Rev. 3 - 2

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# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±12	V		
Continuous Drain Current (Note 5) $V_{GS}$ = -10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ $T_C = +25^{\circ}C$	۱ <sub>D</sub>	-18.0 -14.5 -40	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	IDM	-80	A		
Maximum Continuous Body Diode Forward Current	Is	-2.2	A		
Avalanche Current L=0.1mH	I <sub>AS</sub>	-30	A		
Avalanche Energy L=0.1mH	E <sub>AS</sub>	50	mJ		

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	D	2.3	W
	T <sub>C</sub> = +25°C	PD	41	
Thermal Resistance, Junction to Ambient	(Note 5)	Р	58	°C/W
	(Note 6)	$R_{\theta JA}$	143	
Thermal Resistance, Junction to Case	R <sub>ejc</sub>	3.0		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

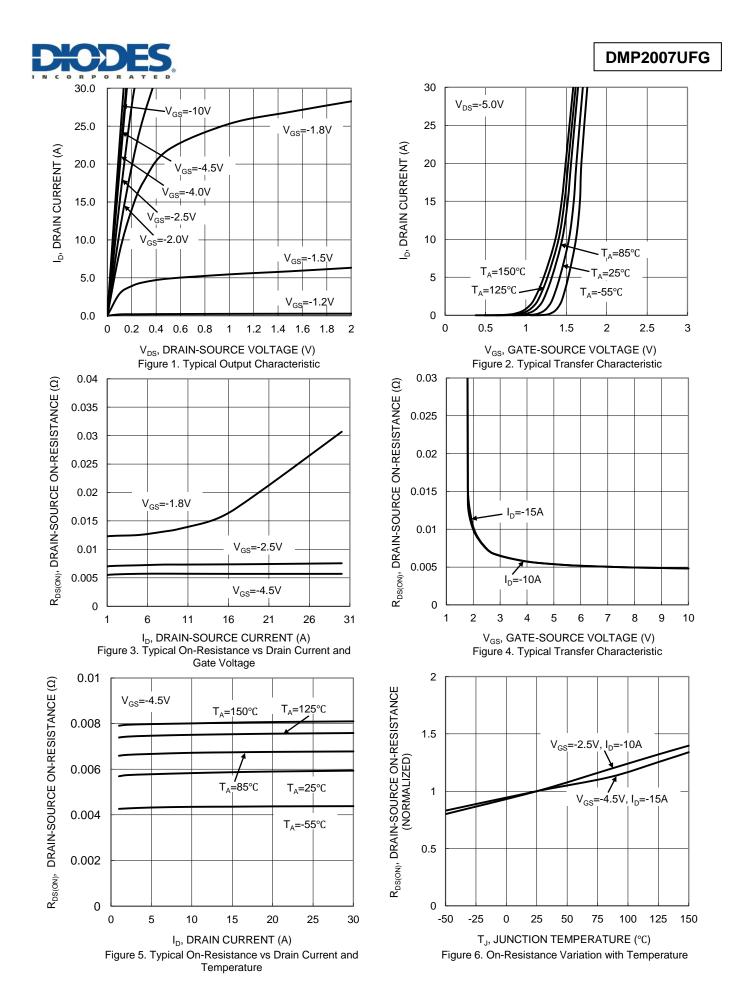
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					•	-
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	_	-1.3	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
		_	4.4	5.5		V <sub>GS</sub> = -10V, I <sub>D</sub> = -15A
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	4.9	7.0	mΩ	$V_{GS} = -4.5V, I_D = -15A$
			6.5	9.0	1	$V_{GS} = -2.5V, I_{D} = -10A$
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -10A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	-	4,621	_		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	Coss		652	_	pF	
Reverse Transfer Capacitance	Crss	_	403	_		
Gate Resistance	RG	_	3.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		39	_		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	85	_	nC	V <sub>DD</sub> = -10V, I <sub>D</sub> = -20A
Gate-Source Charge	Q <sub>qs</sub>		8.3	_	nc	
Gate-Drain Charge	Q <sub>gd</sub>		9.6	_		
Turn-On Delay Time	t <sub>D(ON)</sub>		10.1	_		$V_{GS} = -4.5V, V_{DD} = -10V,$ $R_G = 1\Omega, I_D = -10A$
Turn-On Rise Time	t <sub>R</sub>	_	9.8	_		
Turn-Off Delay Time	t <sub>D(OFF)</sub>		61	_	ns	
Turn-Off Fall Time	t <sub>F</sub>	_	51	_	1	
Reverse Recovery Time	t <sub>RR</sub>		20.1	_	ns	I <sub>F</sub> = -10A, di/dt = 100A/µs
Reverse Recovery Charge	Qrr	_	10.1	_	nC	I <sub>F</sub> = -10A, di/dt = 100A/µs

Notes: 5. R<sub>0JA</sub> is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

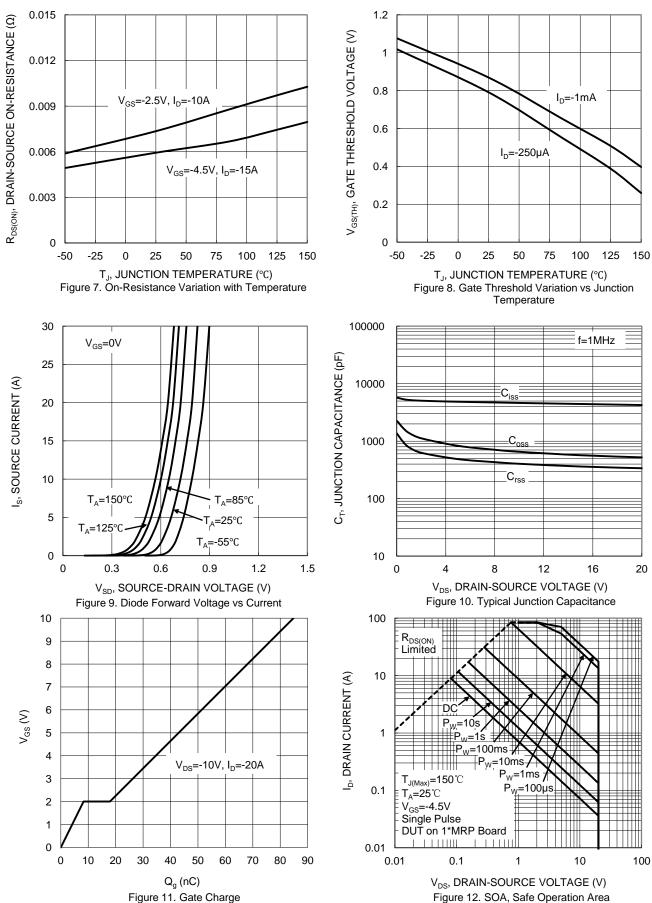
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.







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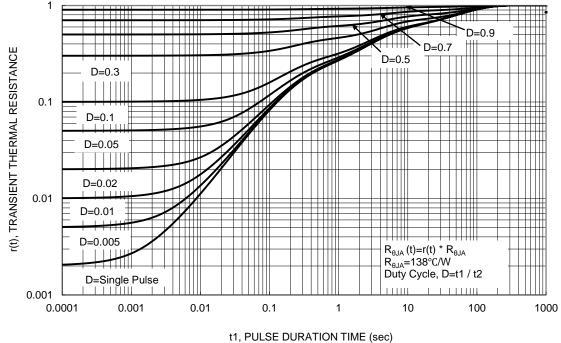
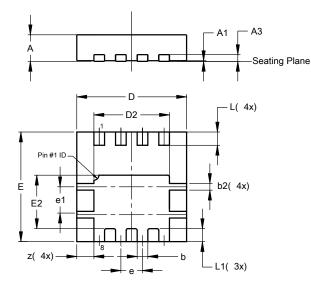


Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

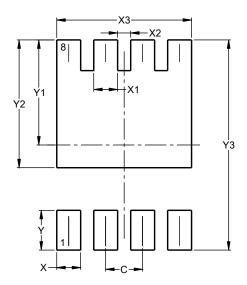
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI <sup>®</sup> 3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
е	-	-	0.65		
e1	0.79	0.89	0.84		
L	0.35	0.45	0.40		
L1	_	—	0.39		
z	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
X3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		



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